

# Midium Power Transistors (80V / 2.5A) 2SCR544D

#### Structure

NPN Silicon epitaxial planar transistor

#### • Features

- 1) Low saturation voltage, typically
- $V_{CE (sat)} = 0.3V (Max.) (I_C / I_B = {}_1A / 50mA)$
- 2) High speed switching

#### Applications

Driver

### Packaging specifications

	Package	CPT3
Туре	Code	TL
	Basic ordering unit (pieces)	2500

#### • Absolute maximum ratings (Ta = 25°C)

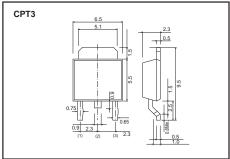
Parameter		Symbol	Limits	Unit
Collector-base voltage		V <sub>CBO</sub>	80	V
Collector-emitter voltage		V <sub>CEO</sub>	80	V
Emitter-base voltage		V <sub>EBO</sub>	6	V
Collector current	DC	Ι <sub>C</sub>	2.5	А
	Pulsed	ا <sub>CP</sub> *1	5	А
Power dissipation		P <sub>D</sub> *2	1	W
		P <sub>D</sub> *3	10	W
Junction temperature		Tj	150	°C
Range of storage temperature		T <sub>stg</sub>	-55 to 150	°C

# \*1 Pw=10ms, Single Pulse

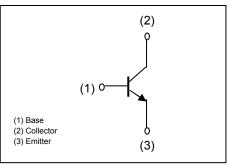
\*2 Mounted on a substrate.

\*3 Tc=25°C

#### • Dimensions (Unit : mm)



#### Inner circuit



# • Electrical characteristic (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	$BV_{CEO}$	80	-	-	V	I <sub>C</sub> = 1mA
Collector-base breakdown voltage	$BV_{CBO}$	80	-	-	V	I <sub>C</sub> = 100μΑ
Emitter-base breakdown voltage	$BV_{EBO}$	6	-	-	V	Ι <sub>Ε</sub> = 100μΑ
Collector cut-off current	I <sub>CBO</sub>	-	-	1	μA	V <sub>CB</sub> = 80V
Emitter cut-off current	I <sub>EBO</sub>	-	-	1	μA	V <sub>EB</sub> = 4V
Collector-emitter staturation voltage	V <sub>CE(sat)</sub> <sup>*1</sup>	-	100	300	mV	I <sub>C</sub> = 1A, I <sub>B</sub> = 50mA
DC current gain	h <sub>FE</sub>	120	-	390	-	V <sub>CE</sub> = 3V, I <sub>C</sub> = 100mA
Transition frequency	f⊤ <sup>*1</sup>	-	280	-	MHz	V <sub>CE</sub> = 10V I <sub>E</sub> =-500mA, f=100MHz
Collector output capacitance	C <sub>ob</sub>	-	16	-	pF	V <sub>CB</sub> = 10V, I <sub>E</sub> =0A f=1MHz
Turn-on time	t <sub>on</sub> *2	-	50	-	ns	1 - 1.20 + - 120mA
Storage time	t <sub>stg</sub> * <sub>2</sub>	-	700	-	ns	I <sub>C</sub> = 1.3A, I <sub>B1</sub> = 130mA, I <sub>B2</sub> =-130mA, V <sub>CC</sub> <u>~</u> 10V
Fall time	t <sub>f</sub> *2	-	40	-	ns	B2 100

\*1 Pulsed

\*2 See switching time test circuit

# • Electrical characteristic curves (Ta = 25°C)

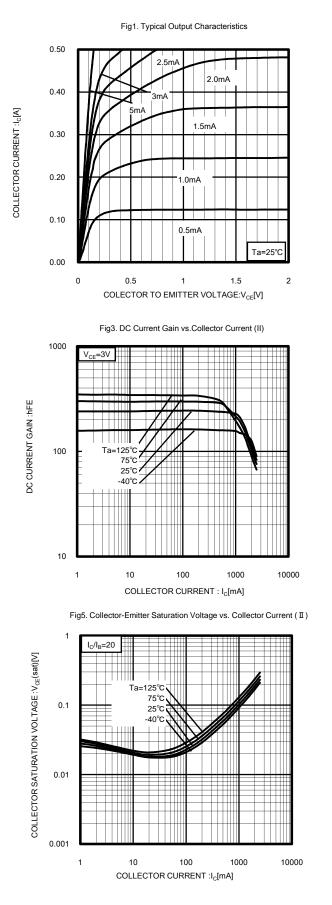
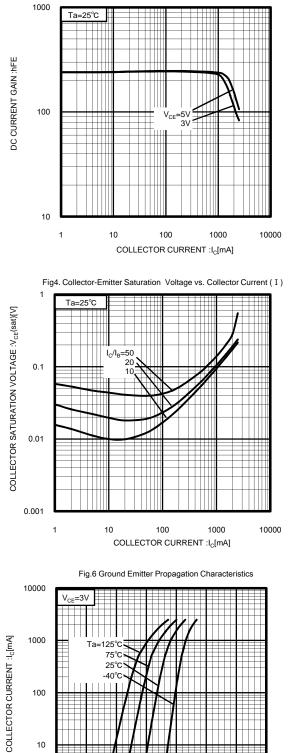
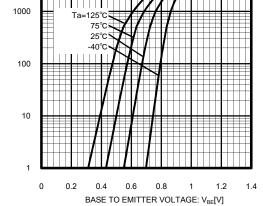
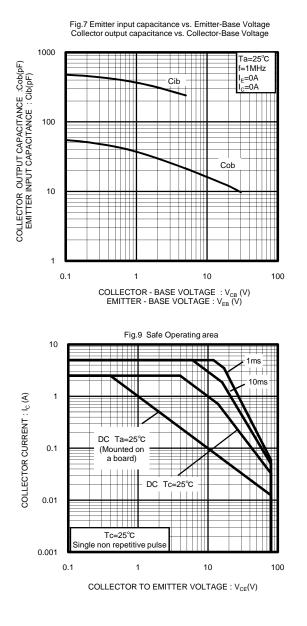
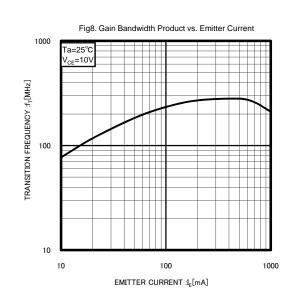


Fig2. DC Current Gain vs. Collector Current (I)

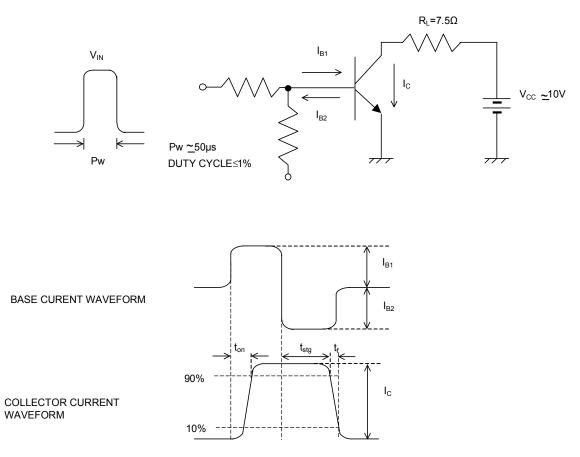








# • Switching time test circuit



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